



# IMPORTANT NOTICE

10 December 2015

## 1. Global joint venture starts operations as WeEn Semiconductors

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As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

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Thank you for your cooperation and understanding,

WeEn Semiconductors





# BYC10DX-600

## Hyperfast power diode

Rev. 1 — 30 June 2011

Product data sheet

## 1. Product profile

### 1.1 General description

Hyperfast power diode in a SOD113 (2-lead TO-220F) plastic package.

### 1.2 Features and benefits

- Isolated plastic package
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

### 1.3 Applications

- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

### 1.4 Quick reference data

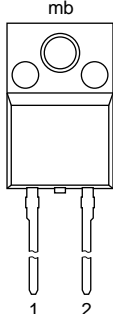
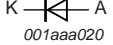
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	-	600	V
$I_{F(AV)}$	average forward current	square-wave pulse; $\delta = 0.5$ ; $T_h = 41$ °C; see <a href="#">Figure 1</a> ; see <a href="#">Figure 2</a>	-	-	10	A
<b>Static characteristics</b>						
$V_F$	forward voltage	$I_F = 10$ A; $T_j = 25$ °C; see <a href="#">Figure 5</a>	-	2	2.5	V
		$I_F = 10$ A; $T_j = 150$ °C; see <a href="#">Figure 5</a>	-	1.4	1.8	V
<b>Dynamic characteristics</b>						
$t_{rr}$	reverse recovery time	$I_F = 10$ A; $V_R = 400$ V; $di_F/dt = 500$ A/ $\mu$ s; $T_j = 25$ °C; see <a href="#">Figure 6</a>	-	18	-	ns



## 2. Pinning information

**Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	n.c.	mounting base; isolated		

**SOD113 (TO-220F)**

## 3. Ordering information

**Table 3. Ordering information**

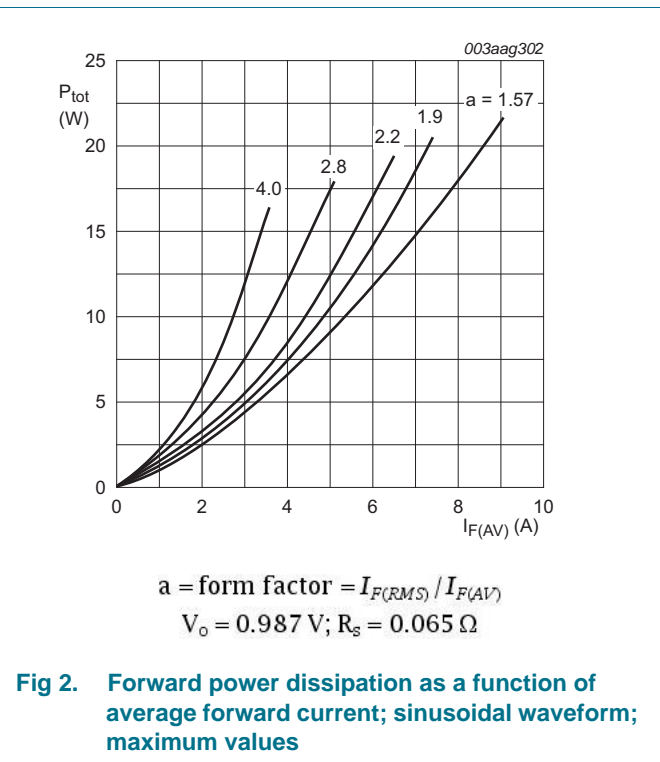
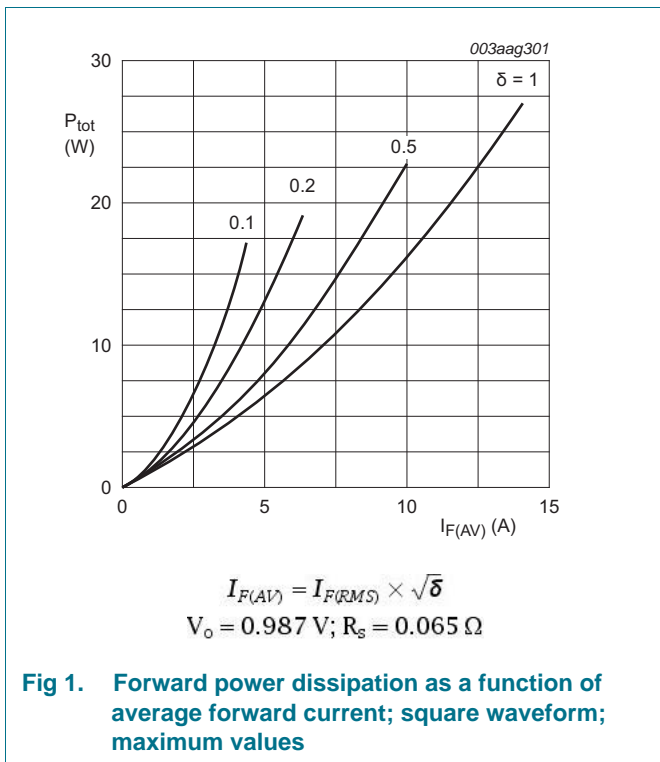
Type number	Package		
	Name	Description	Version
BYC10DX-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

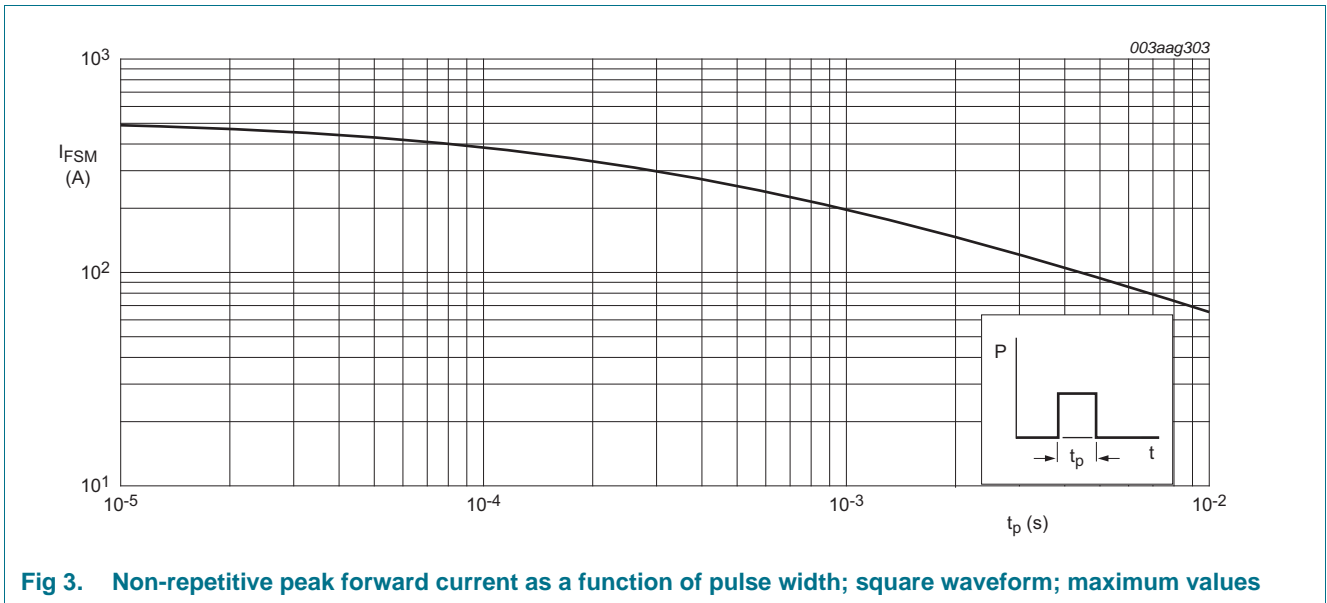
### 4. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
$V_{RWM}$	crest working reverse voltage		-	600	V
$V_R$	reverse voltage	DC	-	500	V
$I_{F(AV)}$	average forward current	square-wave pulse; $\delta = 0.5$ ; $T_h = 41\text{ }^\circ\text{C}$ ; see <a href="#">Figure 1</a> ; see <a href="#">Figure 2</a>	-	10	A
$I_{FRM}$	repetitive peak forward current	square-wave pulse; $\delta = 0.5$ ; $t_p = 25\text{ }\mu\text{s}$ ; $T_h = 41\text{ }^\circ\text{C}$	-	20	A
$I_{FSM}$	non-repetitive peak forward current	$t_p = 10\text{ ms}$ ; sine-wave pulse; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$ ; see <a href="#">Figure 3</a>	-	65	A
		$t_p = 8.3\text{ ms}$ ; sine-wave pulse; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$ ; see <a href="#">Figure 3</a>	-	71	A
$T_{\text{stg}}$	storage temperature		-40	150	$^\circ\text{C}$
$T_j$	junction temperature		-	150	$^\circ\text{C}$





### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	without heatsink compound	-	-	5.9	K/W
		with heatsink compound ; see <a href="#">Figure 4</a>	-	-	4.8	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air		-	60	-	K/W

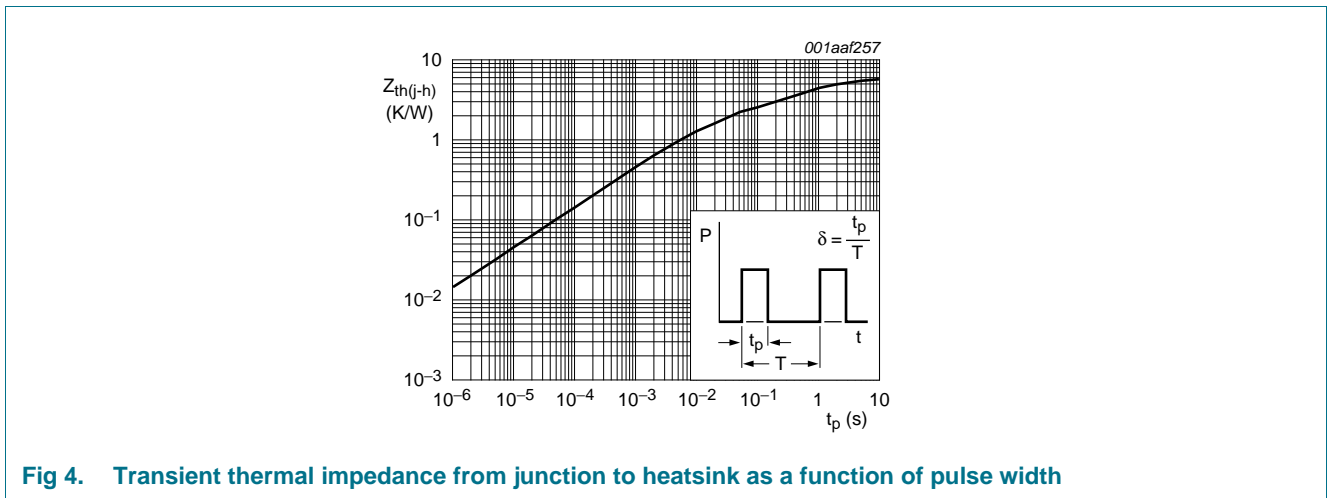


Fig 4. Transient thermal impedance from junction to heatsink as a function of pulse width

### 6. Isolation characteristics

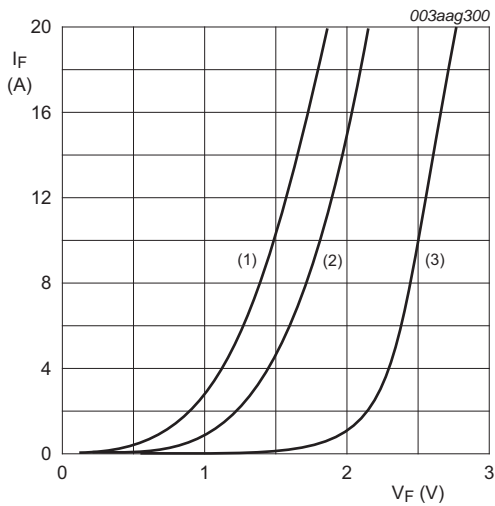
Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
$C_{isol}$	isolation capacitance	f = 1 MHz ; from cathode to external heatsink	-	10	-	pF

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_F$	forward voltage	$I_F = 10\text{ A}; T_j = 25\text{ °C};$ see <a href="#">Figure 5</a>	-	2	2.5	V
		$I_F = 10\text{ A}; T_j = 150\text{ °C};$ see <a href="#">Figure 5</a>	-	1.4	1.8	V
		$I_F = 20\text{ A}; T_j = 150\text{ °C};$ see <a href="#">Figure 5</a>	-	1.7	2.2	V
$I_R$	reverse current	$V_R = 500\text{ V}; T_j = 100\text{ °C}$	-	1.1	3	mA
		$V_R = 600\text{ V}$	-	9	200	$\mu\text{A}$
<b>Dynamic characteristics</b>						
$t_{rr}$	reverse recovery time	$I_F = 1\text{ A}; V_R = 30\text{ V}; dI_F/dt = 50\text{ A}/\mu\text{s}; T_j = 25\text{ °C};$ see <a href="#">Figure 6</a>	-	15	30	ns
		$I_F = 10\text{ A}; V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 25\text{ °C};$ see <a href="#">Figure 6</a>	-	18	-	ns
$I_{RM}$	peak reverse recovery current	$I_F = 10\text{ A}; V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 100\text{ °C};$ see <a href="#">Figure 6</a>	-	9.5	12	A
		$I_F = 10\text{ A}; V_R = 400\text{ V}; dI_F/dt = 50\text{ A}/\mu\text{s}; T_j = 125\text{ °C};$ see <a href="#">Figure 6</a>	-	3	7.5	A
$V_{FR}$	forward recovery voltage	$I_F = 10\text{ A}; dI_F/dt = 100\text{ A}/\mu\text{s}; T_j = 25\text{ °C};$ see <a href="#">Figure 7</a>	-	8	11	V



(1)  $T_j = 150\text{ °C};$  typical values;  
 (2)  $T_j = 150\text{ °C};$  maximum values;  
 (3)  $T_j = 25\text{ °C};$  maximum values;  
 $V_o = 0.987\text{ V}; R_s = 0.065\ \Omega$

Fig 5. Forward current as a function of forward voltage

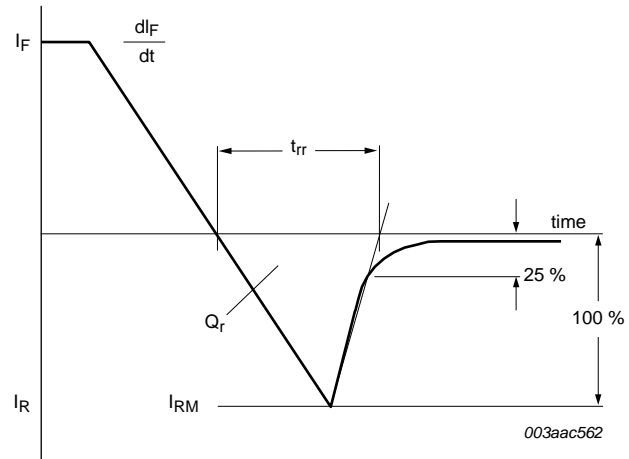


Fig 6. Reverse recovery definitions; ramp recovery

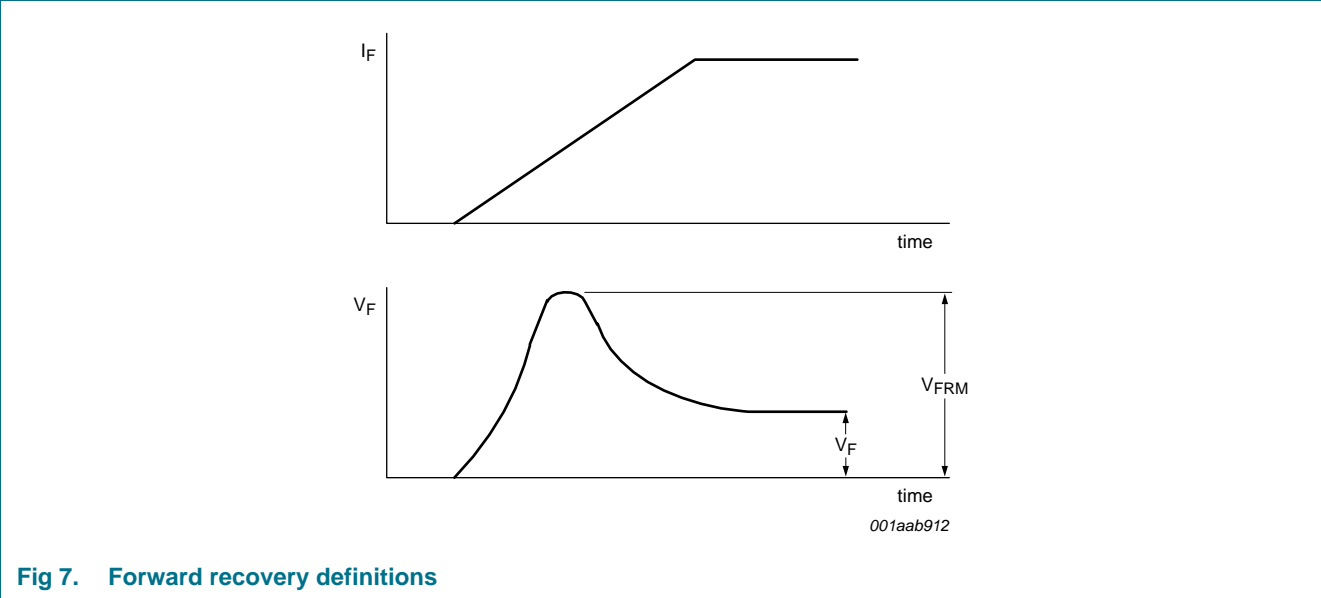


Fig 7. Forward recovery definitions



8. Package outline

Plastic single-ended package; isolated heatsink mounted;  
1 mounting hole; 2-lead TO-220 'full pack'

SOD113

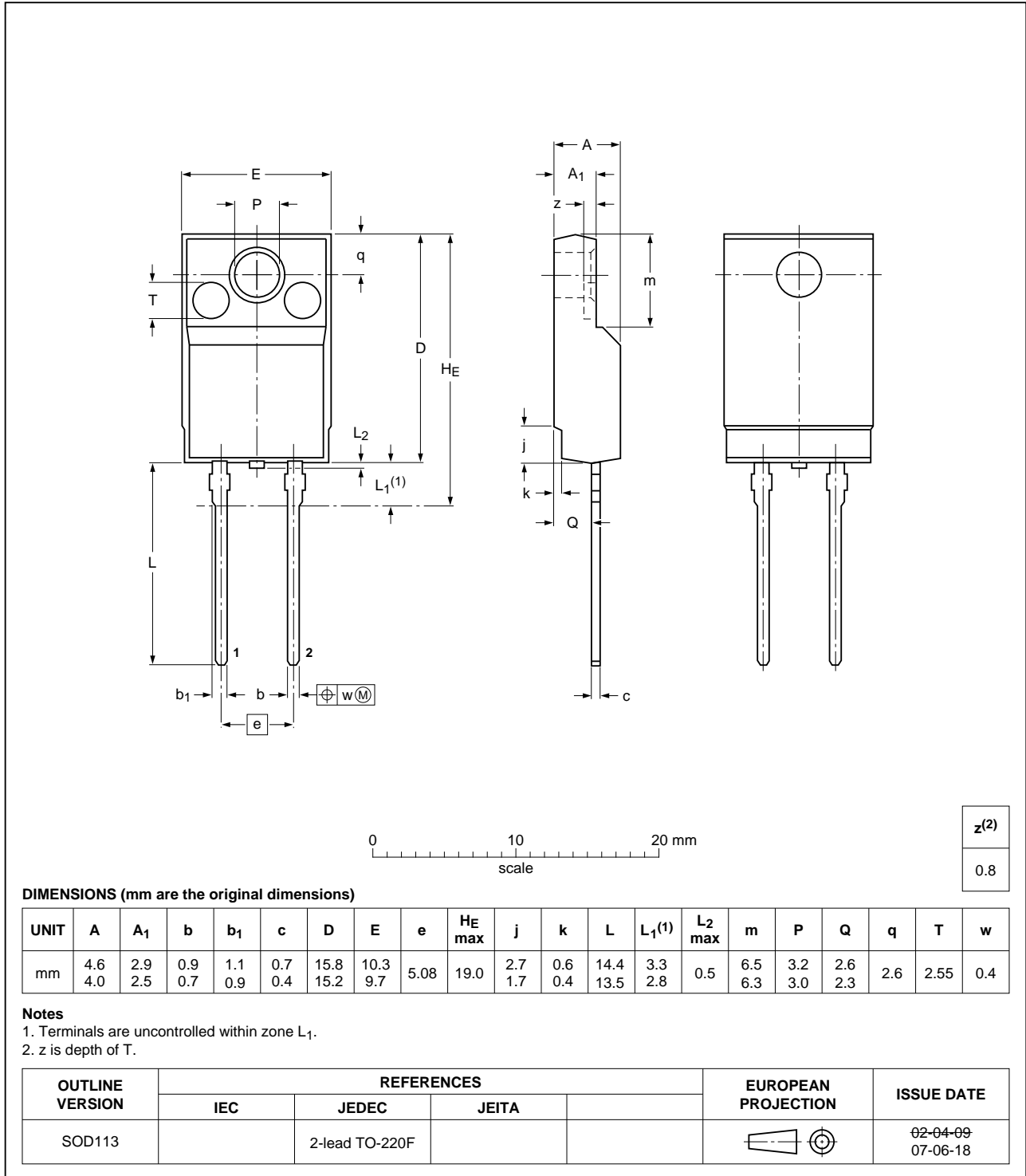


Fig 8. Package outline SOD113 (TO-220F)

## 9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYC10DX-600 v.1	20110630	Product data sheet	-	-

## 10. Legal information

### 10.1 Data sheet status

Document status <sup>[1]</sup> <sup>[2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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